

# Chih-Chiang Yang

## List of Publications by Year in descending order

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Version: 2024-02-01

18  
papers

219  
citations

1040056

9  
h-index

996975

15  
g-index

18  
all docs

18  
docs citations

18  
times ranked

302  
citing authors

#	ARTICLE	IF	CITATIONS
1	Silver-Doped Citrus Pectin Resistive Random Access Memory with Multilevel Characteristics. ECS Journal of Solid State Science and Technology, 2022, 11, 055003.	1.8	1
2	Cs <sub>4</sub> PbBr <sub>6</sub> /CsPbBr <sub>3</sub> Nanocomposites for All-Inorganic Electroluminescent Perovskite Light-Emitting Diodes. ACS Applied Nano Materials, 2020, 3, 11760-11768.	5.0	21
3	Ultraviolet Photodetection Application in Magnesium Indium Oxide Thin Film Transistors via Co-Sputtering Deposition. Applied Sciences (Switzerland), 2020, 10, 5128.	2.5	4
4	ALD Al <sub>2</sub> O <sub>3</sub> gate dielectric on the reduction of interface trap density and the enhanced photo-electric performance of IGO TFT. RSC Advances, 2020, 10, 9902-9906.	3.6	6
5	Ambient-Processed, Additive-Assisted CsPbBr <sub>3</sub> Perovskite Light-Emitting Diodes with Colloidal NiOx Nanoparticles for Efficient Hole Transporting. Coatings, 2020, 10, 336.	2.6	10
6	Amorphous MgInO Ultraviolet Solar-Blind Photodetectors. IEEE Access, 2019, 7, 103250-103254.	4.2	7
7	TiO <sub>2</sub> Nano Flowers Based EGFET Sensor for pH Sensing. Coatings, 2019, 9, 251.	2.6	32
8	Impact of Oxygen Vacancy on the Photo-Electrical Properties of In <sub>2</sub> O <sub>3</sub> -Based Thin-Film Transistor by Doping Ga. Materials, 2019, 12, 737.	2.9	13
9	Effect of Oxygen Concentration Ratio on a Ga <sub>2</sub> O <sub>3</sub> -Based Resistive Random Access Memory. IEEE Access, 2019, 7, 175186-175191.	4.2	8
10	The Effect of Oxygen Vacancy Concentration on Indium Gallium Oxide Solar Blind Photodetector. IEEE Transactions on Electron Devices, 2018, 65, 1817-1822.	3.0	30
11	Electron Field Emission Enhancement Based on Al-Doped ZnO Nanorod Arrays With UV Exposure. IEEE Transactions on Electron Devices, 2018, 65, 251-256.	3.0	4
12	Hybrid PVK: OXD-7: QDs Emitting Layer for High Color Purified Quantum Dot Light Emitting-Diode. , 2018, , .		0
13	UV-Enhanced 2-D Nanostructured ZnO Field Emitter With Adsorbed Pt Nanoparticles. IEEE Electron Device Letters, 2018, 39, 1932-1935.	3.9	6
14	Low-Frequency Noise Performance of Al-Doped ZnO Nanorod Photosensors by a Low-Temperature Hydrothermal Method. IEEE Transactions on Electron Devices, 2017, 64, 3206-3212.	3.0	22
15	The Effect of Ga Doping Concentration on the Low-Frequency Noise Characteristics and Photoresponse Properties of ZnO Nanorods-Based UV Photodetectors. IEEE Journal of Selected Topics in Quantum Electronics, 2015, 21, 233-239.	2.9	13
16	Enhanced Field Emission Properties of Ag Nanoparticle-Decorated ZnO Nanorods Under Ultraviolet Illumination. IEEE Transactions on Electron Devices, 2015, 62, 2300-2305.	3.0	20
17	Impact of preparation condition of ZnO electron transport layer on performance of hybrid organic-inorganic light-emitting diodes. Journal of Applied Physics, 2014, 115, 083109.	2.5	14
18	Novel Ga-ZnO Nanosheet Structures Applied in Ultraviolet Photodetectors. IEEE Photonics Technology Letters, 2014, 26, 1317-1320.	2.5	8